NSN 5961-01-095-8468

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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204aa

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

850.0 collector to emitter voltage, dc and 450.0 collector-to-emitter substaining voltage, with specified circuit between base and emitter

and 400.0 collector-to-emitter, substaining voltage, base open-circuited and 9.0 emitter to base voltage, dc

Current Rating Per Characteristic:

Between 8.00 amperes source cutoff current and 8.00 amperes source cutoff current

Power Rating Per Characteristic:

125.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0